

30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

70 A

Features

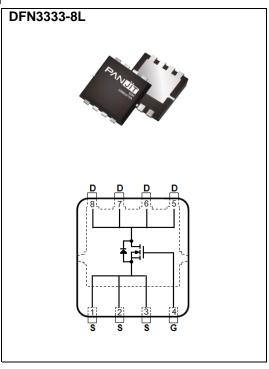
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@10A<3.8m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@5A<5.5m\Omega$
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20		
Continuous Drain Current	T _C =25°C	I _D	70	А	
	T _C =100°C		44		
Pulsed Drain Current(Note 1)	T _C =25°C	I _{DM}	280		
Power Dissipation	T _C =25°C	Po	39	W	
	Tc=100°C		15.6		
Continuous Drain Current	T _A =25°C	I _D	16	А	
	T _A =70°C		13		
Power Dissipation	T _A =25°C	-	2.0	10/	
Power Dissipation	T _A =70°C	PD	1.3	W	
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	R ₀ JC	3.21		
	Junction to Ambient	R _{θJA}	62.5	°C/W	

Limited only By Maximum Junction Temperature



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static			_			
Drain-Source Breakdown Voltage	BV _{DSS}	BV _{DSS} V _{GS} =0V, I _D =250uA		-	-	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1	1.6	2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =10A	-	3.3	3.8	mΩ
		V _{GS} =4.5V, I _D =5A	-	5.0	5.5	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Q_g	V _{DS} =15V, I _D =24A, V _{GS} =4.5V ^(Note 2,3)	-	23	-	nC
Gate-Source Charge	Q_gs		-	8	-	
Gate-Drain Charge	Q_gd		-	9	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	2436	-	pF
Output Capacitance	Coss		-	306	-	
Reverse Transfer Capacitance	Crss		-	196	-	
Turn-On Delay Time	td _(on)	V _{DS} =15V, I _D =15A, V _{GS} =10V, R _G =1Ω	-	32	-	ns
Turn-On Rise Time	t _r		-	169	-	
Turn-Off Delay Time	td _(off)		-	232	-	
Turn-Off Fall Time	t _f	(14010 2,5)	-	170	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	70	А
Diode Forward Current	Is					
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.66	1.0	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

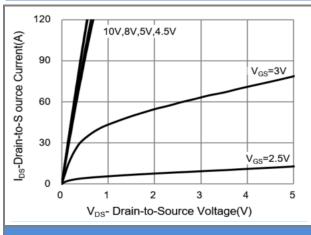


Fig.1 On-Region Characteristics

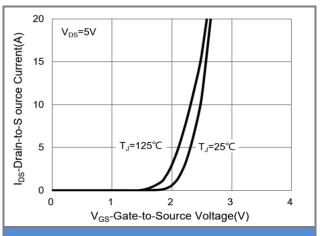


Fig.2 Transfer Characteristics

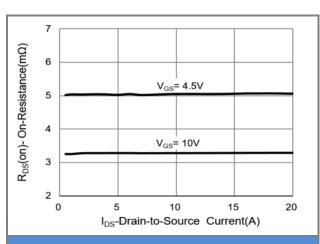


Fig.3 On-Resistance vs. Drain Current

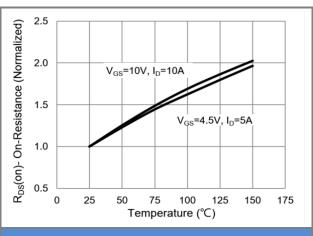
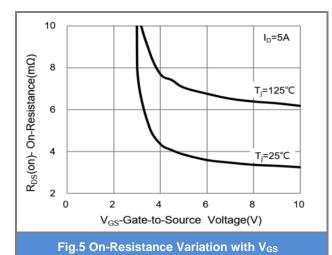


Fig.4 On-Resistance vs. Junction temperature



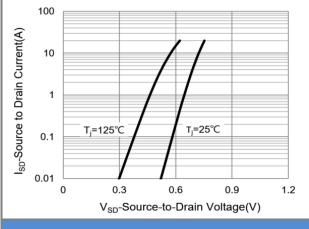


Fig.6 Source-Drain Diode Forward Voltage



TYPICAL CHARACTERISTIC CURVES

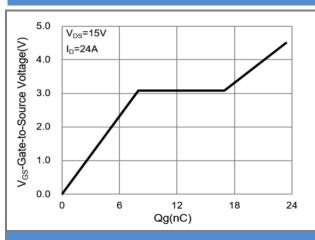


Fig.7 Gate-Charge Characteristics

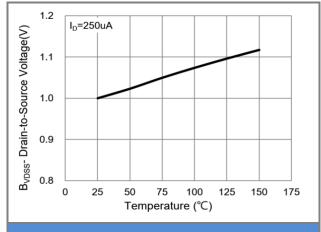


Fig.8 Breakdown Voltage Variation vs. Temperature

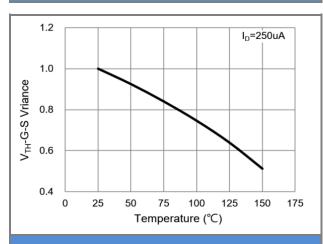


Fig.9 Threshold Voltage Variation with Temperature

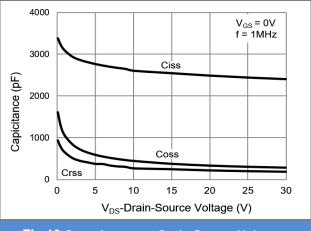
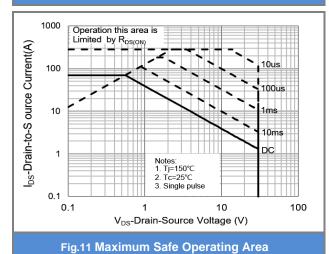


Fig.10 Capacitance vs. Drain-Source Voltage





TYPICAL CHARACTERISTIC CURVES

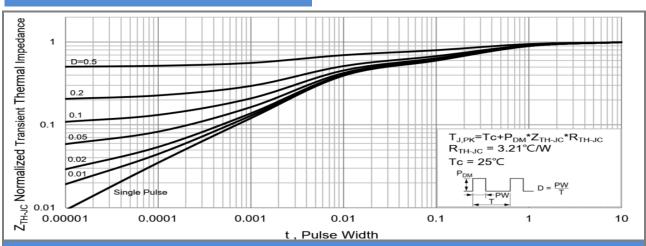


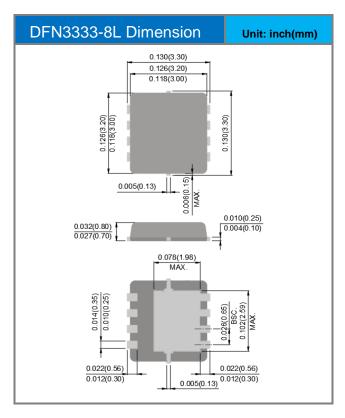
Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

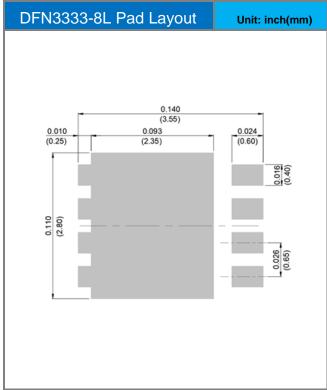


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4402P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4402	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout







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